

QUESTにおけるトロイダル分割型ダイバータバイアスによる周辺・SOLプラズマ制御の初期実験と今後の計画

Initial Experiment and Future Plan of Toroidally Segmented-Divertor Biasing for Edge-SOL Plasma Control in QUEST

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JSPS #26630476

はじめに

➤ 定常熱負荷制御の課題

ITERではWダイバータ板の健全性保持=>定常熱負荷上限: $\leq 10 \text{ MW/m}^2$

=>部分的 or 完全非接触ダイバータ(Partially/fully detached divertor)運転が必須.

(課題)非接触ダイバータ運転条件下での高性能Hモードの,準定常維持は極めて困難

非接触プラズマの低温フロントは不安定で小さな外乱で容易にX点に到達

=> Hモード性能の大幅な低下

(対策)低密度で部分的非接触ダイバータ+ ???

<本研究の目的>

➤ 過渡的熱負荷制御の課題

ELM (edge localized modes) 等による熱負荷許容値: $\leq 20 \text{ MW/m}^2$.

=> ELM抑制や影響緩和のELM制御 => 3D磁場(RMPs, nRMPs) 制御は進展

DIII-D, JET, AUG, MAST, NSTX, LHD

ELM自身によるSOL電流生成 => RMP生成とダイバータ熱負荷分布に影響

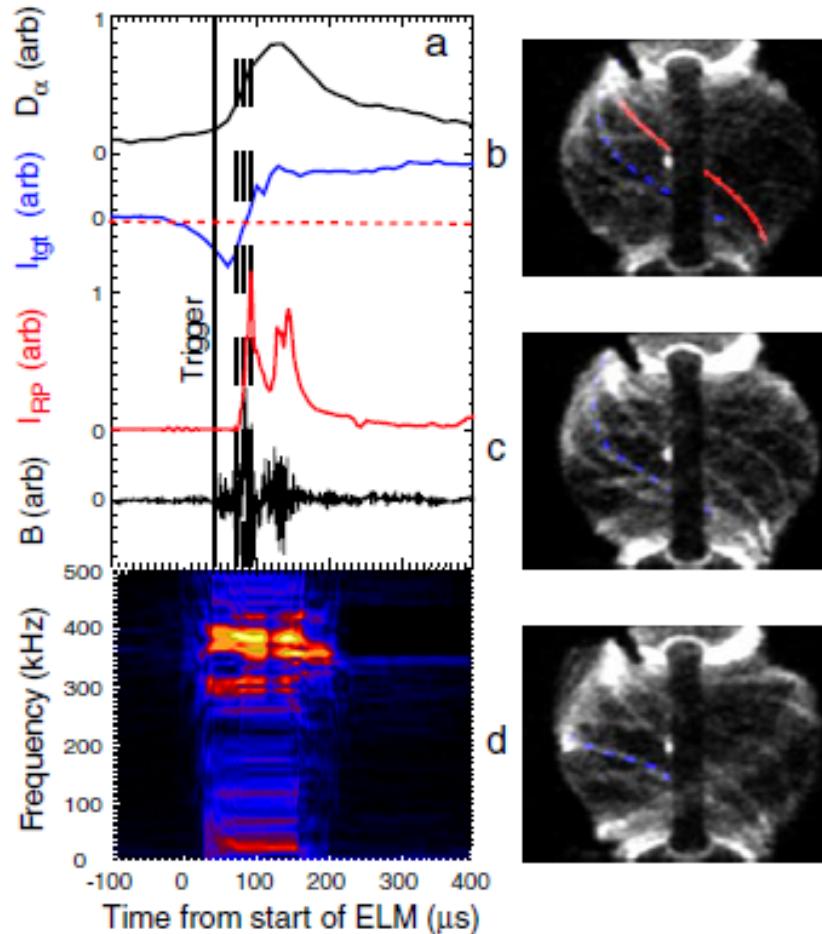
T. Eich et al., PRL 2003, Takahashi et al., PRL 2008, Kirk et al., PRL 2006, J.W. Ahn et al., NF 2014.

(課題)容器内接地RMPコイルはDEMOで使用不可

=> 外部制御したSOL電流によるRMP生成 <本研究の目的>

ELMによるSOL電流の誘起の例(1)

MAST



I_{tgt} : SOL current measured by a shunt resistor at the target plate

Negative (anti-parallel to I_p) at the onset of an ELM

Positive (parallel to I_p) around the peak and decay phase

Transient SOL currents are carried by ELM-generated filaments

Kirk et al., PRL 2006

本研究の目的

＜手法＞トロイダル方向に分割したダイバータ板の位相制御電気的バイアス法

(1) SOLプラズマの径方向輸送の増大=> 熱流束減衰長 λ_q の増大
乱流輸送の増大や ExB ドリフトの増大)

駆動乱流の候補 (collisional drift waves, current convective mode, resistive interchange mode, rippling mode, K-H instabilities ...)

主にQUESTでPoP実験

(2) 位相制御したSOL 電流駆動によるRMP生成=>ELM制御

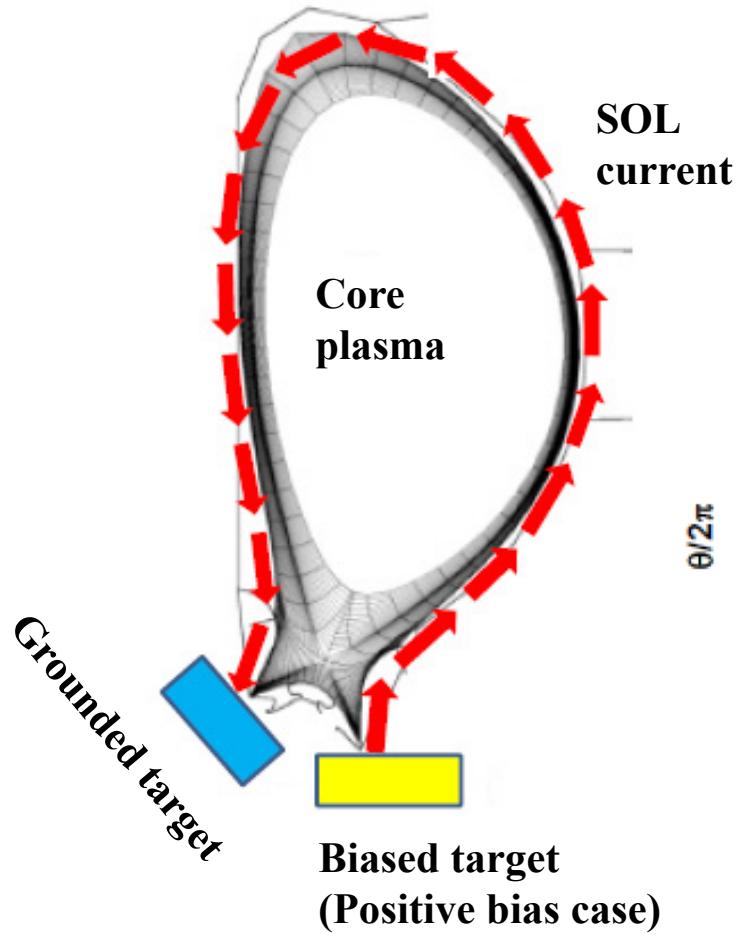
$q_{\text{SOL}} \sim q_{95}$ なので本質的にRMPとなる

SOL電流はHモードペデスタルに近接

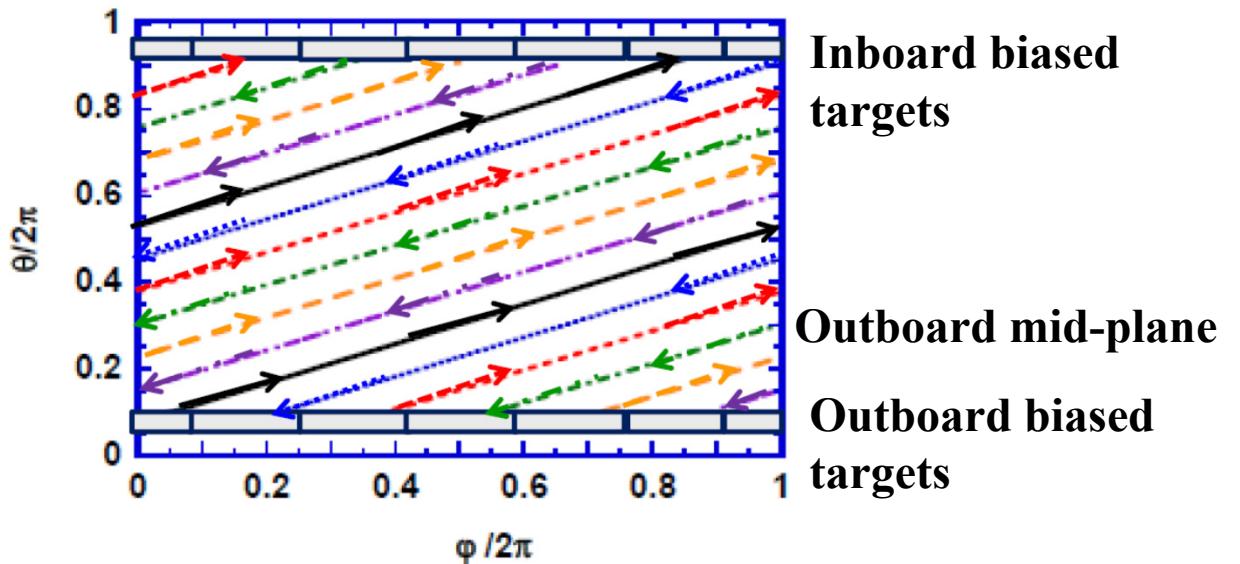
数10kAの電流で $b_{mn}/B_t = (2-4) \times 10^{-4}$ [ELM制御閾値]を実現可能

ELMy Hモードプラズマでテスト

トロイダル分割型ダイバータバイアス法による SOL電流駆動とRMP生成モデル



Method: Electric biasing of toroidally segmented divertor targets against the vacuum vessel with appropriate phasing



[Example] Inboard-outboard both-side biasing for generation of $n=3$ RMPs

One-side biasing
(Both-side biasing is also possible)

トロイダル分割型ダイバータバイアス法による 駆動SOL電流値の評価

Magnitude of SOL Currents

Ion saturation current: $i_{is} \cong 0.61Zen_i \sqrt{\frac{T_e + T_i}{m_i}}$ (Assump.)

Electron saturation current: $i_{es} \cong \sqrt{\frac{m_i}{m_e}} i_{is} \sim 68i_{is} \Rightarrow i_{es} \cong 10i_{is}$

Biasing voltage: $V_{bias} \geq \alpha \mathcal{R}_{\parallel} I_{SOL} + \kappa T_e, \kappa=4\sim5$

[Ohmic drop, $0 < \alpha < 1$]

[Potential drop in sheath]

トロイダル分割型ダイバータバイアス法による 駆動SOL電流の経路長の評価

Path Length of SOL Currents

(1) Collisionless SOL : $A_{\parallel}\Gamma_{\parallel} + A_{\perp}\Gamma_{\perp} = 0$ (\Leftarrow “Large area Langmuir probe”)

$$A_{\parallel} = dh ; \quad A_{\perp} = 2(d+h)L_{\parallel f}; \quad \Gamma_{\parallel} = \frac{1}{4}n v_{\parallel}; \quad \Gamma_{\perp} = -D_{\perp} \nabla n$$

$$\Rightarrow L_{\parallel f} = \frac{d^2 h v_{\parallel}}{8(d+h)D_{\perp}} \quad \text{where } L_{\parallel ef}(\text{electrons}) >> L_{\parallel if}(\text{ion})$$

(2) Collisional SOL: $L_{\parallel ec}$ for electrons; $L_{\parallel ic}$ for ions

$$L_{\parallel ec} = \sqrt{\lambda_{ei} L_{\parallel f}}, \quad \lambda_{ei}: \text{mean free path}$$

S.A. Cohen, JNM 1978; P.C. Stangeby, JPD 1985

(3) Connection length in the SOL: $L_c \sim 2\pi R q_{SOL}$

In QUEST

◆ Scenario I: SOL, $T_e \sim 10-20$ eV, $n_e \sim 5 \times 10^{16} \text{ m}^{-3}$, $q \lesssim 10$, $D_{\perp} = D_B \sim 2 \text{ m}^2/\text{s}$

$$L_c = 2\pi R q \sim 50 \text{ m}, \lambda_{ei} \sim 20 \text{ m}$$

$$L_{\parallel f_el} = 18 \text{ m} \Rightarrow L_{\parallel c_el} = 19 \text{ m} < L_c; i_{is} = 0.2 \text{ kA/m}^2 (I_{is} \sim 0.06 \text{ A})$$

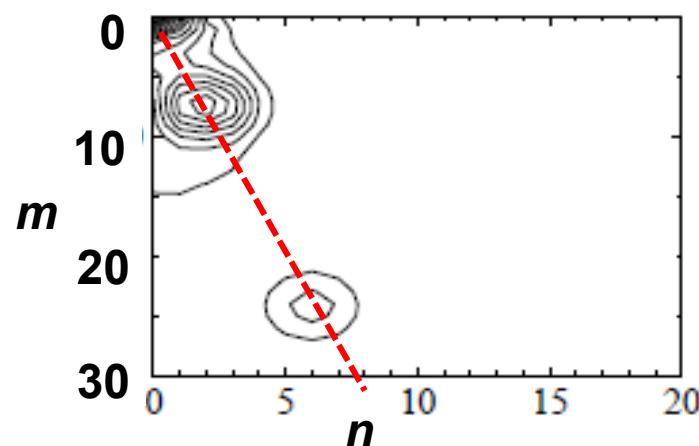
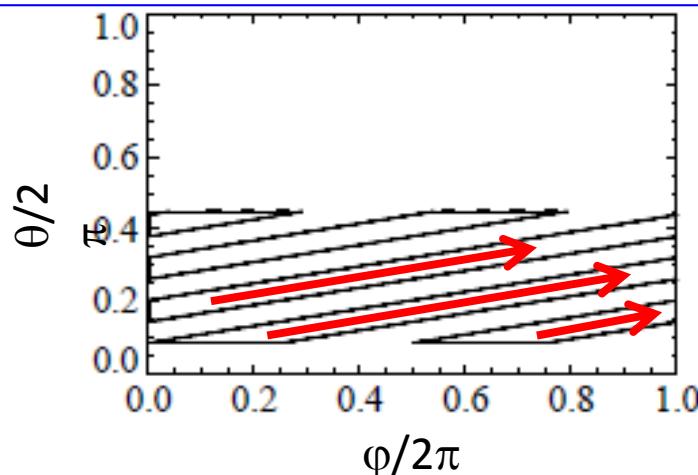
$$I_{SOL} = i_{es} S \sim 10 i_{is} S \sim 0.6 \text{ A}$$

(Similar to detached divertor like without much ionization process)

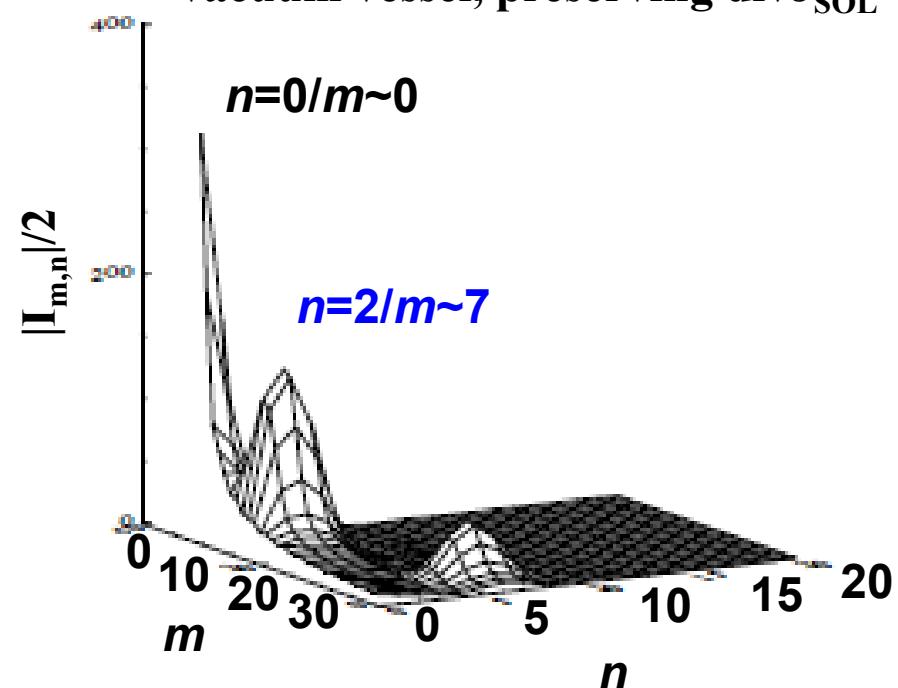
◆ Scenario II: Increase in h , T_e and decreased n_e , $q \Rightarrow L_{\parallel c_el} > L_c$

トロイダル分割型ダイバータバイアス法で生成される SOL電流群のフーリエ成分

Example of Single Null Divertor on
 $L_{\parallel c_el} < L_c$
① Single null divertor
② Outboard target biasing (PFPF)



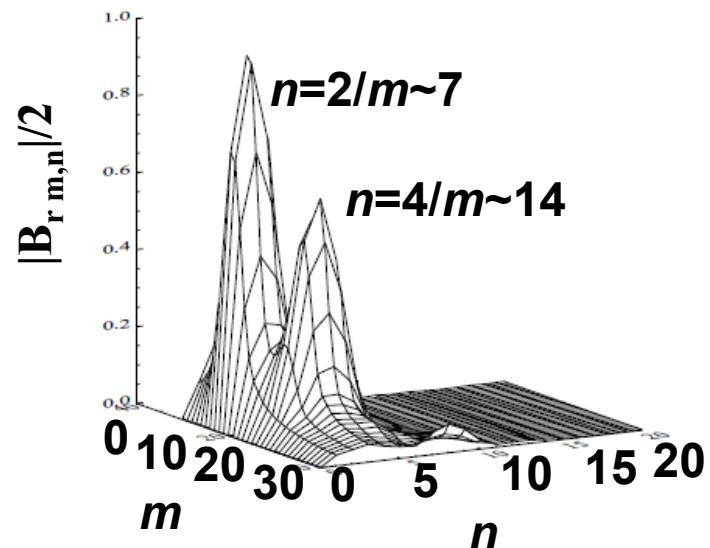
$q_{SOL} \sim 3.5$
Collisional SOL: $L_{\parallel ec}/L_c = 0.44$
Assumption: Return current flows only
radially toward the grounded
vacuum vessel, preserving $\text{div}J_{SOL}=0$



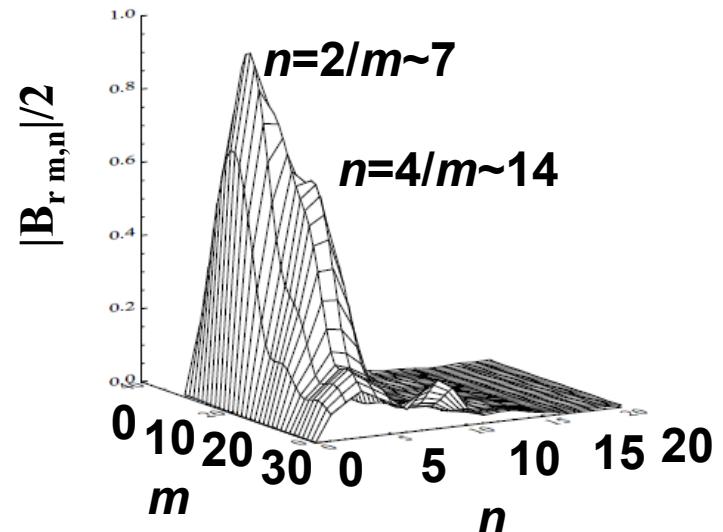
Fourier components are nearly dominated
by the components with $m/n \sim q_{95}$, although
appreciable $m=0$ component exists.

トロイダル分割型ダイバータバイアス法による 駆動SOL電流群の作る径方向磁場のフーリエ成分

Case A: $L_{\parallel ec}/L_c=0.44$



Case B: $L_{\parallel ec}/L_c=0.15$

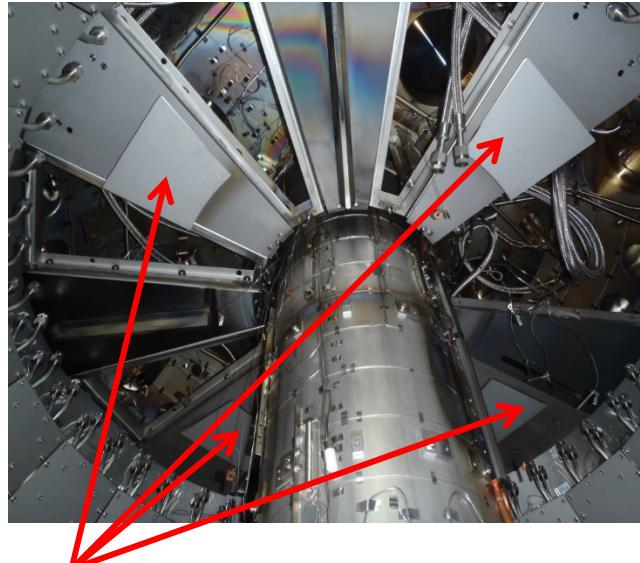


If the collisional path length of the SOL current is in the range of $0.1L_c < L_{\parallel c_el} < L_c$, $n=2$ RMP can reach the necessary level for ELM control when the distance between the SOL current layer and pedestal is $\sim 0.05\langle a \rangle$.

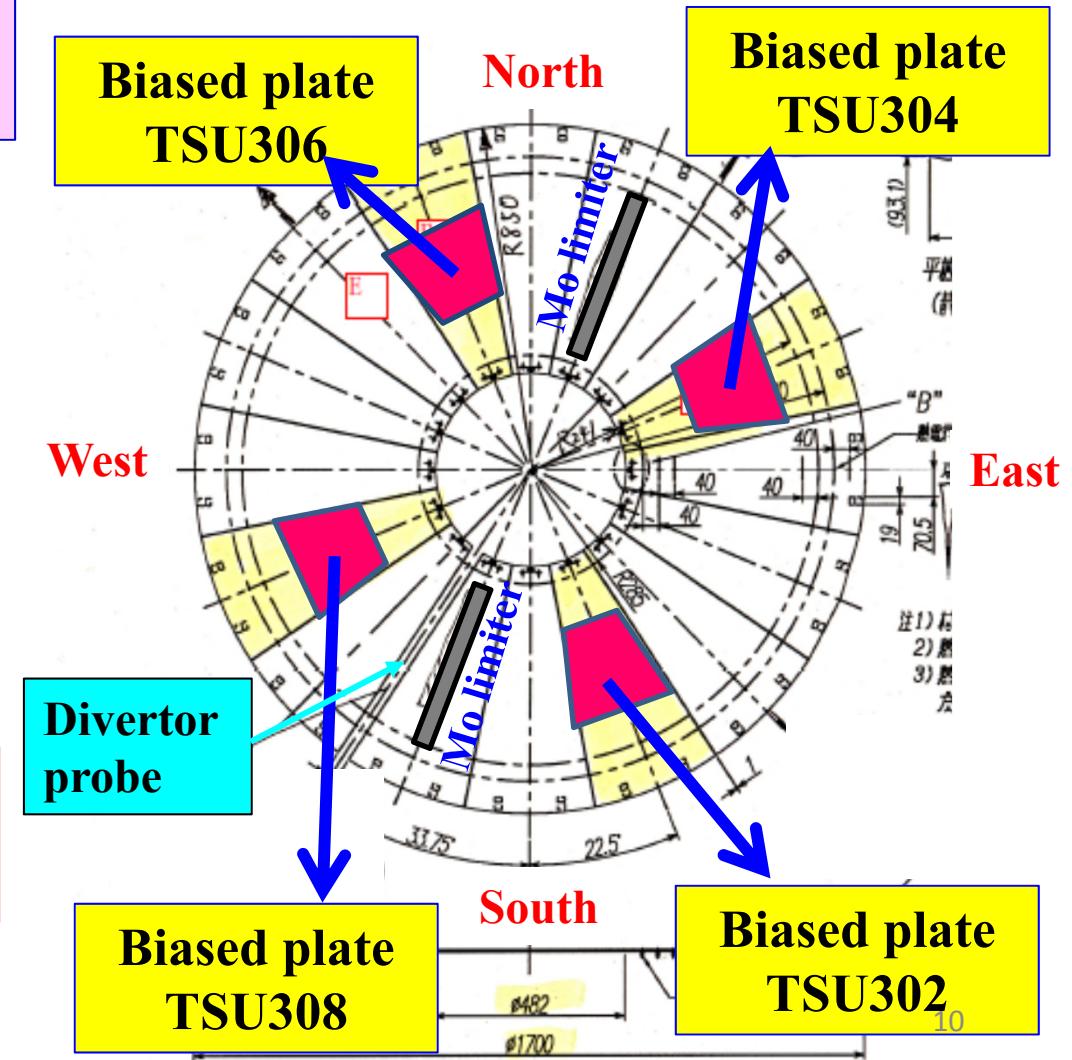
QUESTでのトロイダル分割ダイバータバイアス実験 --- バイアス板の設置---

QUEST(RIAM, Kyusyu Univ., Japan)

$B_t = 0.25$ T at $R = 0.64$ m; $R = 0.76 - 0.80$ m
 $a = 0.38 - 0.45$ m; $I_p = 66$ kA $\Rightarrow 100$ kA

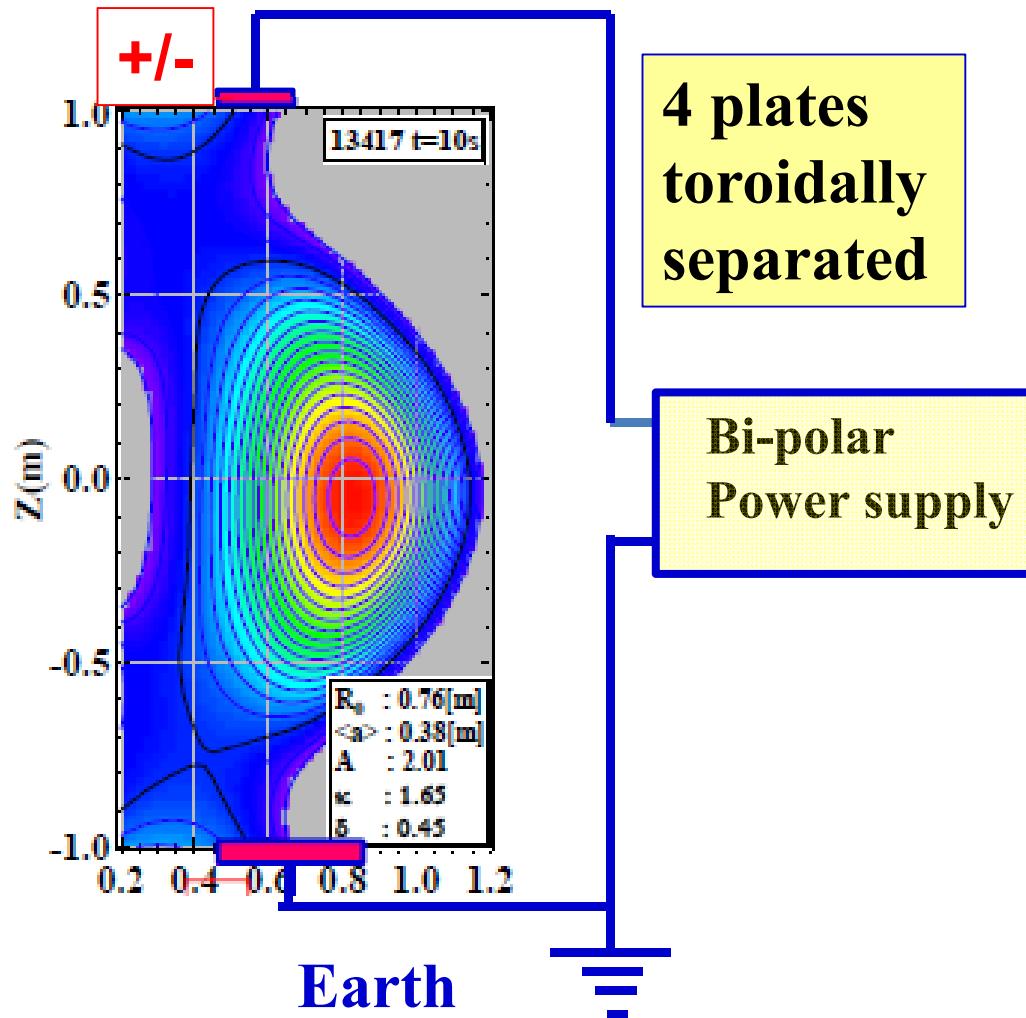


Upper divertor targets for phased biasing
(Operation scenarios:
4 plates for n=1 and n=2 RMPs)



電気的バイアス法

P/N biasing



Voltage application between
divertor plates and vacuum
vessel

Bi-polar power supply

$-75V \leq V \leq +75V$ or
 $-25V \leq V \leq +125V$
 $|I| \leq 7A$

frequency: DC-250 kHz

SOL current Phasing:

P-P-P-P $\Rightarrow n=4\varnothing b_r$

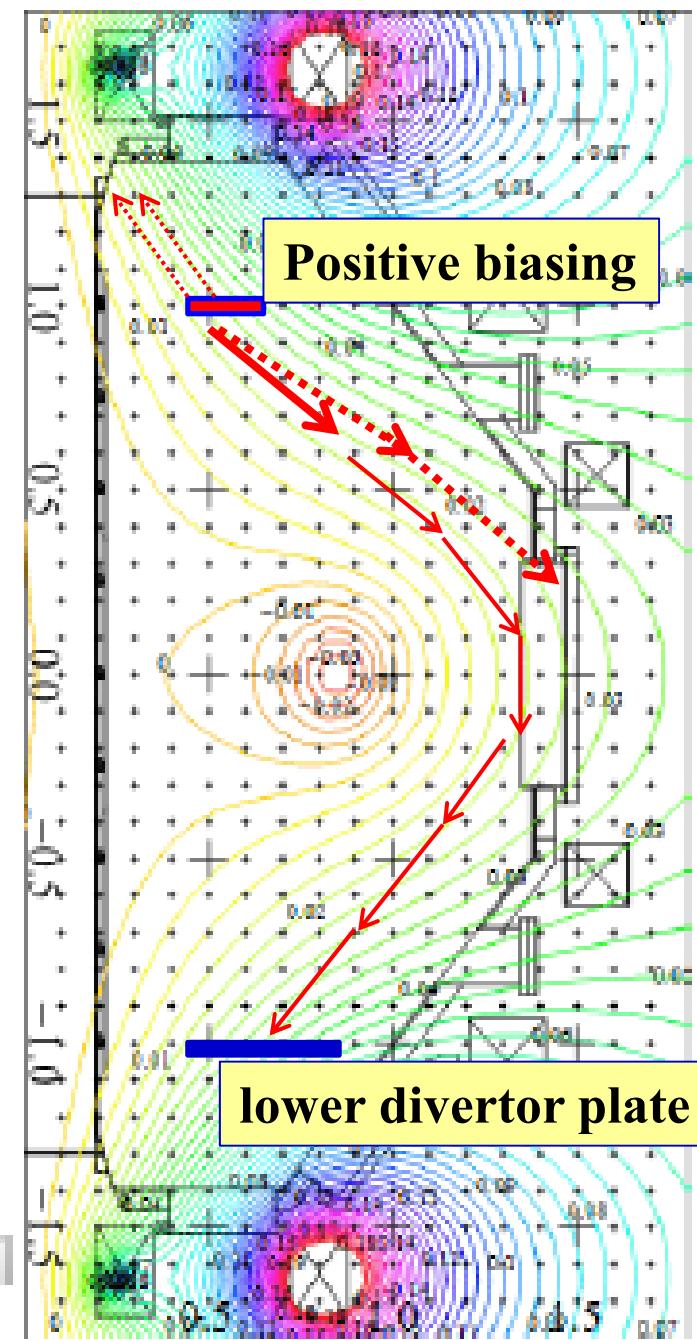
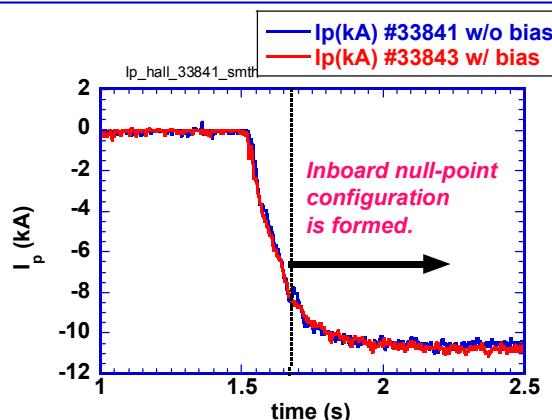
P-F-P-F $\Rightarrow n=2$

P-P-F-F $\Rightarrow n=1$

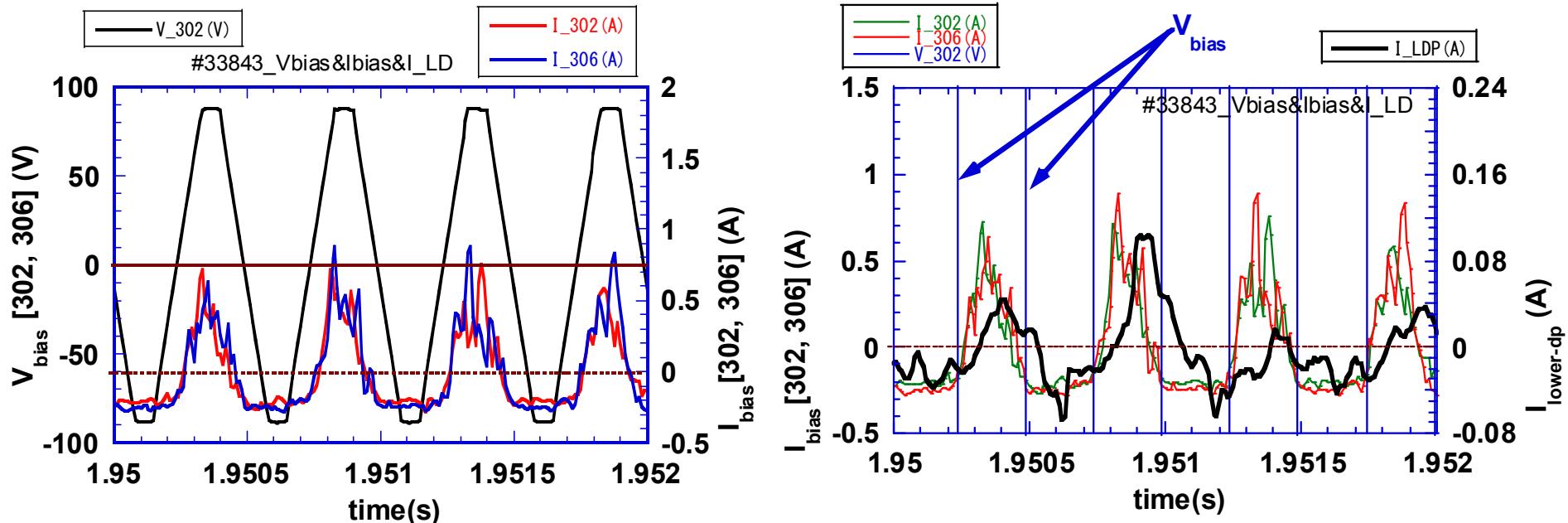
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実験条件

- ◆ SOL plasma parameters (assumed):
 $T_e \sim 10-20 \text{ eV}$, $n_e \sim 5 \times 10^{16} \text{ m}^{-3}$, $R \sim 0.8 \text{ m}$,
 $q \lesssim 10$, $B_t = 0.1-0.3 \text{ T}$, $I_p \sim 10 \text{ kA}$ (Inner X config)
 $L_c = 2\pi R q \sim 50 \text{ m}$, $\lambda_{ei} \sim 20 \text{ m}$
- @Further assumptions: $d = 0.03 \text{ m}$,
 $h = L_t \sin \theta_{in} \sim 0.2 \sin(3^\circ) \sim 0.01 \text{ m}$, $D_\perp = D_B \sim 2 \text{ m}^2$
- ◆ Current path length:
 $L_{f,el} = 18 \text{ m} \Rightarrow L_{c,el} = 19 \text{ m} < L_c \Rightarrow$
Flow leakage from the biased flux tube?
- ◆ Driven currents:
 $i_{is} = 0.2 \text{ kA/m}^2$, $S = dh \sim 1 \times 10^{-4} \text{ m}^2 \Rightarrow I_{is} \sim 0.06 \text{ A}$
 \Rightarrow Expected current for each biased target
 $I_{SOL} = i_{es} S \sim 10 i_{is} S \sim 0.6 \text{ A}$



上側バイアス板及び接地電位下側ダイバータ板 で観測された電流



Observed current flows out the biased 302 or 306 plate:

Positive biasing phase $\Rightarrow I_{bias} \sim 0.6-0.7 A$ (from Plate to SOL plasma)

Negative biasing phase $\Rightarrow I_{bias} \sim -0.2 A$ (from SOL plasma to Plate)

Observed current flows in the lower plate reaches $\sim 0.1 A$ ($\sim 7\%$ of the total driven current by biasing target), synchronizing with the biasing voltage waveform.

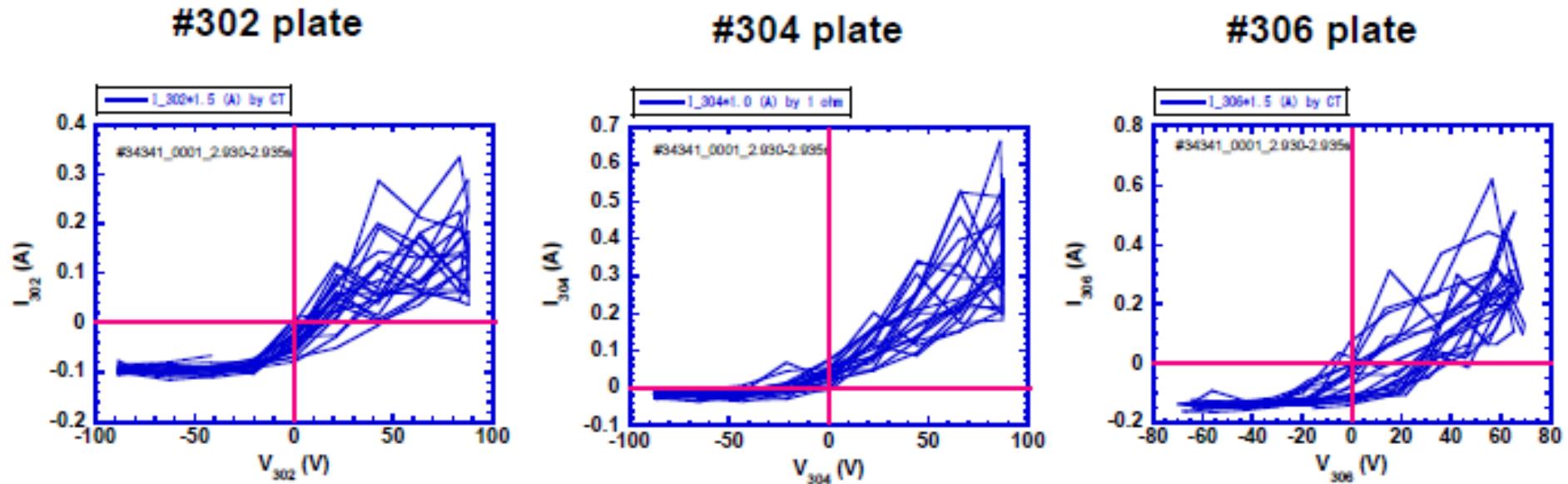
$=>$ It seems to be consistent with the situation of $L_{c,el} < L_c$.

- * Where does the other part of current flow to ?

- * The current rise time is $\sim 0.1ms$ to $\sim 0.2 ms$ for the biasing voltage.

(L and \mathfrak{R} of the biased flux tube: $L \sim 60 \mu H$, $\mathfrak{R} \sim 0.6 \Omega \Rightarrow \tau = L/\mathfrak{R} \sim 0.1 ms$)

バイアス板でのV-I特性



Single probe characteristics are found between the applied voltage and current through the biased plate.

Note that the voltage is monitored at the bi-polar power supply, ~ 10 m away from the biased plate.

Ion saturation current is close to the predicted one using plausible assumption.

Floating potential is positive for the vessel potential. It seems to be dependent on the plate.

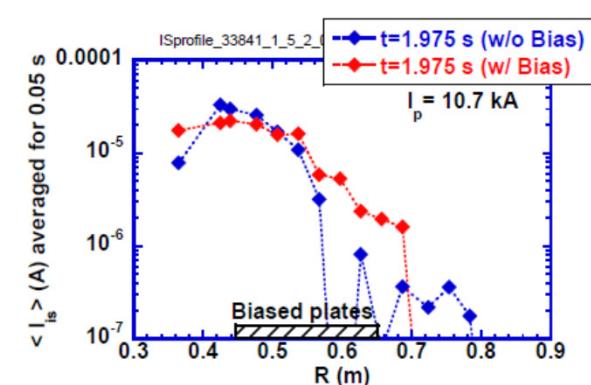
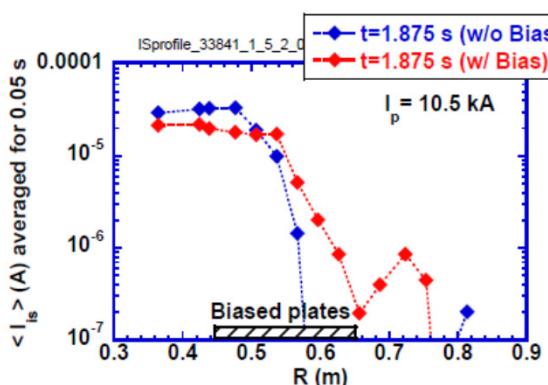
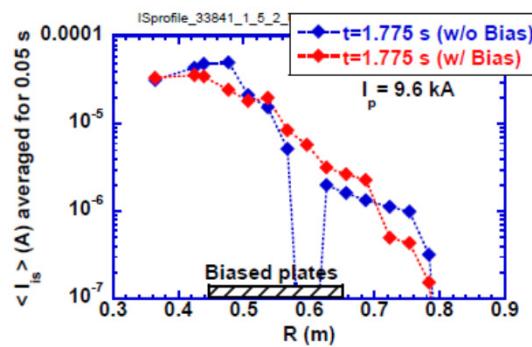
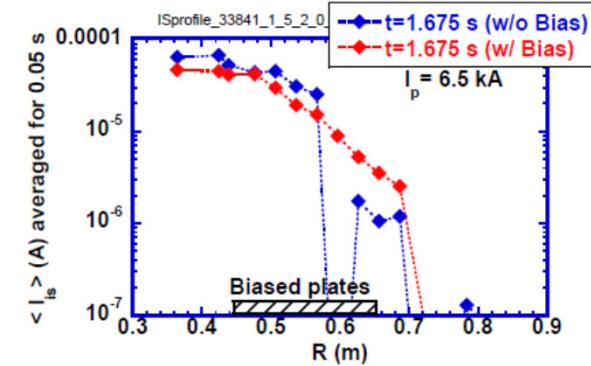
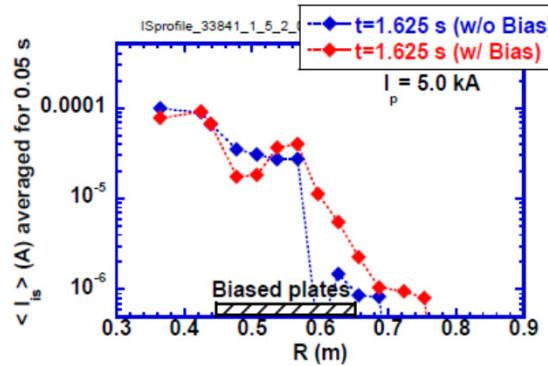
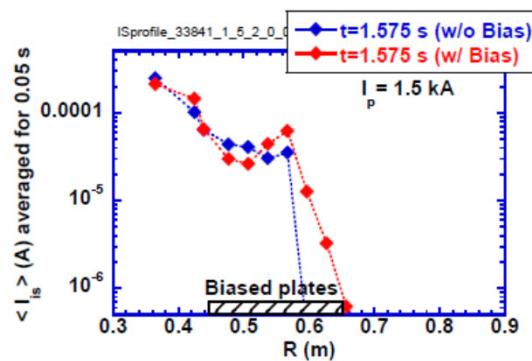
No clear saturation is observed in the positive biasing.

トロイダル分割ダイバータバイアスのダイバータ粒子束への影響

Biassing off (#33841)

Biassing on (#33843)

$\langle I_{is} \rangle$: averaged over $t-0.025s$ to $t+0.025s$



Divertor biasing in the upper divertor plates slightly expands the ion saturation current profiles measured at the upper divertor region.

Mechanisms: $E \times B$ effect or enhanced radial transport
(+ biasing => outward ExB drift)

まとめ

- トロイダル方向に分割されたダイバータ板のバイアス法による(1) SOLの径方向熱輸送の増大によるダイバータ熱流束制御法の開発と(2) SOL電流フィラメント群の能動的駆動によるRMP生成を狙った研究計画と初期実験結果を示した。
- <初期実験条件>
8.2GHz RF生成内側X点配位プラズマ($I_p \sim 10$ kA, $B_t = 0.25$ T ($R = 0.64$ m))
バイアス条件: ± 75 V, 2 kHzの鋸歯状波
- <実験結果 >
駆動SOL電流: $I_{biased\ plate} \sim 1$ A (flow-out) at $V_{bias} = +75$ V (positive biasing),
 ~ -0.2 A (flow-in) at $V_{bias} = -75$ V (negative biasing)
 $I_{lower\ target} \sim 0.1$ A (flow-in) (slow rise of ~ 0.1 - 0.2 ms)
 \Rightarrow Only ~ 7 % of total currents driven by biasing
- # ダイバータ粒子。熱流速分布への影響:
2プレートのダイバータバイアスにより、ダイバータ粒子束のR方向分布の拡張を示唆する結果を得た!!

今後の計画

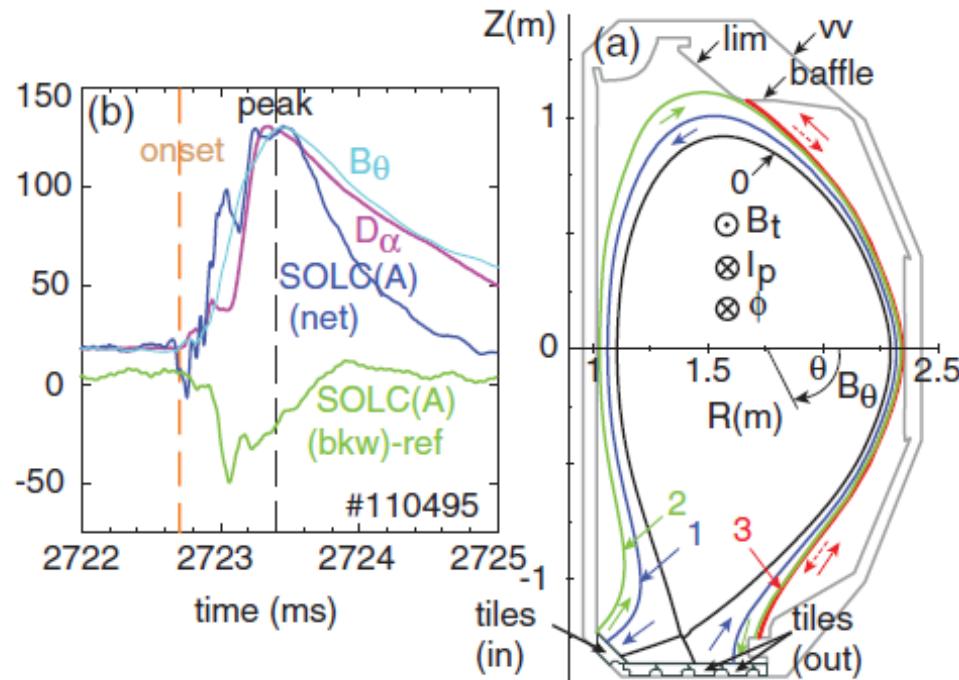
2017年度の計画

1. バイアス駆動電流のSOL以外への漏えい防止策を施す
(改造バイアス板を2016年度中に設置予定)
2. バイアス板のプローブ特性とプラズマパラメータ測定
 T_e , n_e , $L_{//e}$, SOL電流生成の磁場等
3. ダイバータ粒子束の大きい高密度プラズマでの直流と交流
(up to ~100 kHz)バイアスの影響を調べる(粒子束分布と
SOL中の揺動計測 (可動LP+MPアレイ設置を計画)
4. SOL電流路中の計測と生成RMP強度分布計測 (可動
LP+MPアレイ設置を計画)
5. 上側X点及びダブルX点配位での実験

Backup

ELMによるSOL電流の誘起の例(2)

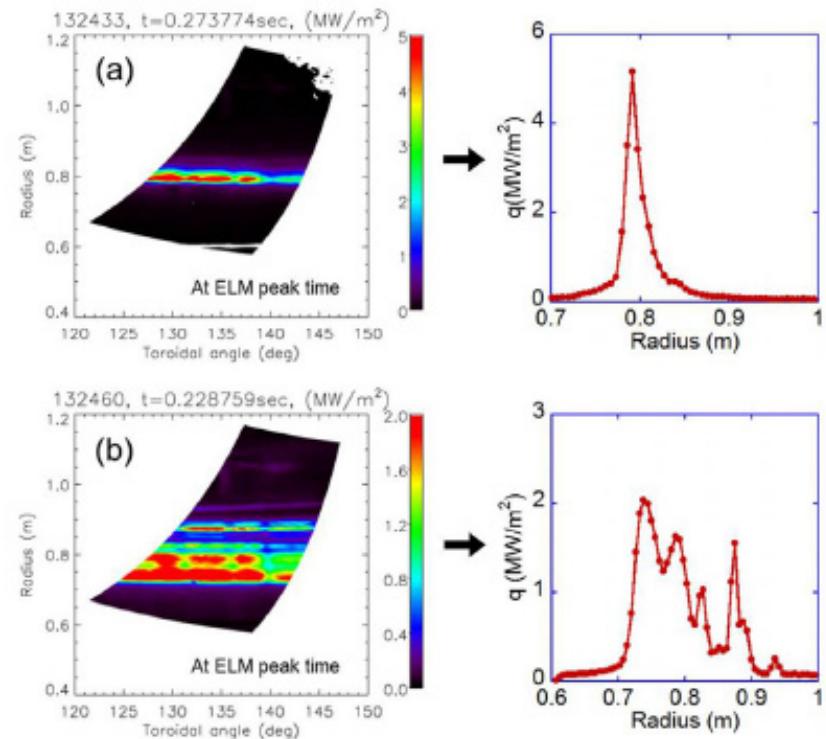
DIII-D



SOL currents (SOLCs) are induced by an ELM, having a short negative spike and decays with a similar waveform to the D_α emission.

Takahashi et al., PRL 2008

NSTX

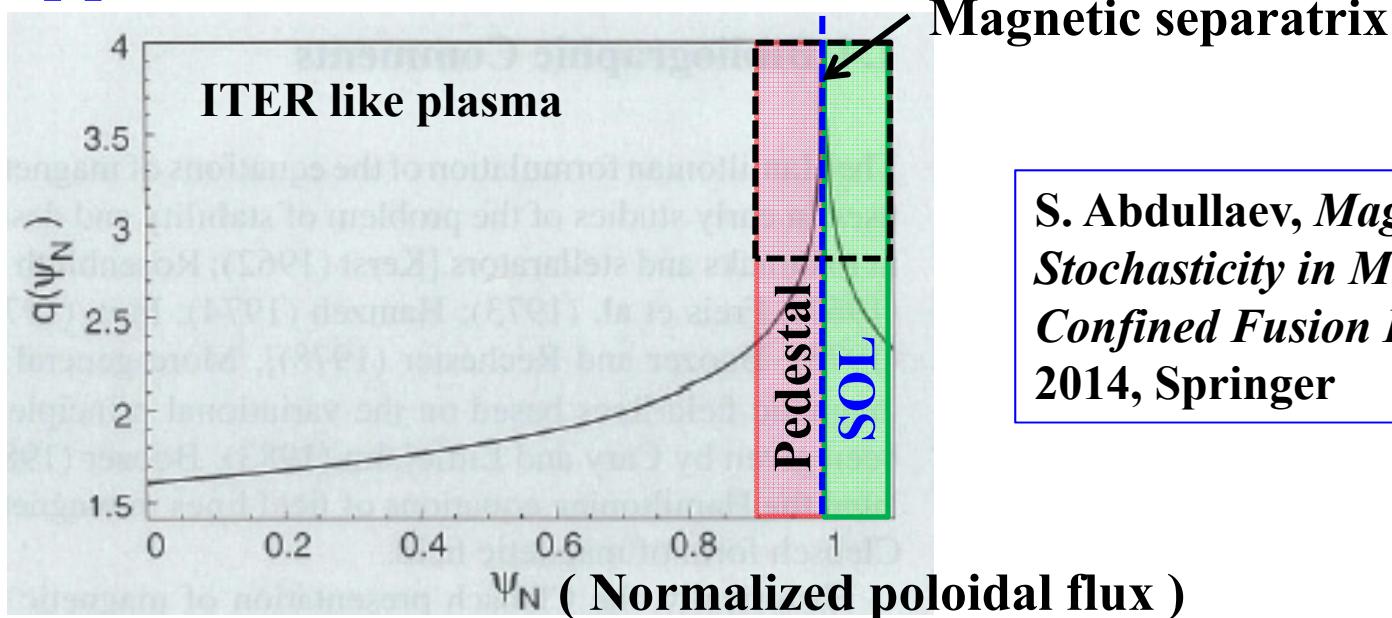


Broadening & splitting of the heat load patterns on the targets were observed during ELMs in NSTX, depending on the number of the filamentary striations.

J.W. Ahn et al., NF 2014

トカマクプラズマの閉じた磁気面領域のq分布と SOL領域での拡張q分布

q-profile in the tokamak SOL



S. Abdullaev, *Magnetic Stochasticity in Magnetically Confined Fusion Plasmas*, 2014, Springer

Effective q value in SOL just outside the separatrix (q_{SOL}) is close to q_{95} just inside the separatrix.
⇒ SOL current can generate magnetic perturbations which nearly resonate with the field in the pedestal region.

QUESTの仮定プラズマパラメータで評価した電流値と電流路長(計算例)

Path Length of SOL Currents

(1) Collisionless SOL : $A_{\parallel}\Gamma_{\parallel} + A_{\perp}\Gamma_{\perp} = 0$ (*<= “Large area Langmuir probe”*)

$$A_{\parallel} = dh ; \quad A_{\perp} = 2(d+h)L_{\parallel f}; \quad \Gamma_{\parallel} = \frac{1}{4}n v_{\parallel}; \quad \Gamma_{\perp} = -D_{\perp} \nabla n$$

$$\Rightarrow L_{\parallel f} = \frac{d^2 h v_{\parallel}}{8(d+h)D_{\perp}} \quad \text{where } L_{\parallel ef}(\text{electrons}) >> L_{\parallel if}(\text{ion})$$

(2) Collisional SOL: $L_{\parallel ec}$ for electrons; $L_{\parallel ic}$ for ions

$$L_{\parallel ec} = \sqrt{\lambda_{ei} L_{\parallel f}}, \quad \lambda_{ei}: \text{mean free path}$$

S.A. Cohen, JNM 1978; P.C. Stangeby, JPD 1985

(3) Connection length in the SOL: $L_c \sim 2\pi R q_{SOL}$

In QUEST

◆ Scenario I: SOL, $T_e \sim 10-20$ eV, $n_e \sim 5 \times 10^{16} \text{ m}^{-3}$, $R \sim 0.8 \text{ m}$, $q \lesssim 10$, $B_t = 0.1-0.3 \text{ T}$

$$L_c = 2\pi R q \sim 50 \text{ m}, \lambda_{ei} \sim 20 \text{ m}$$

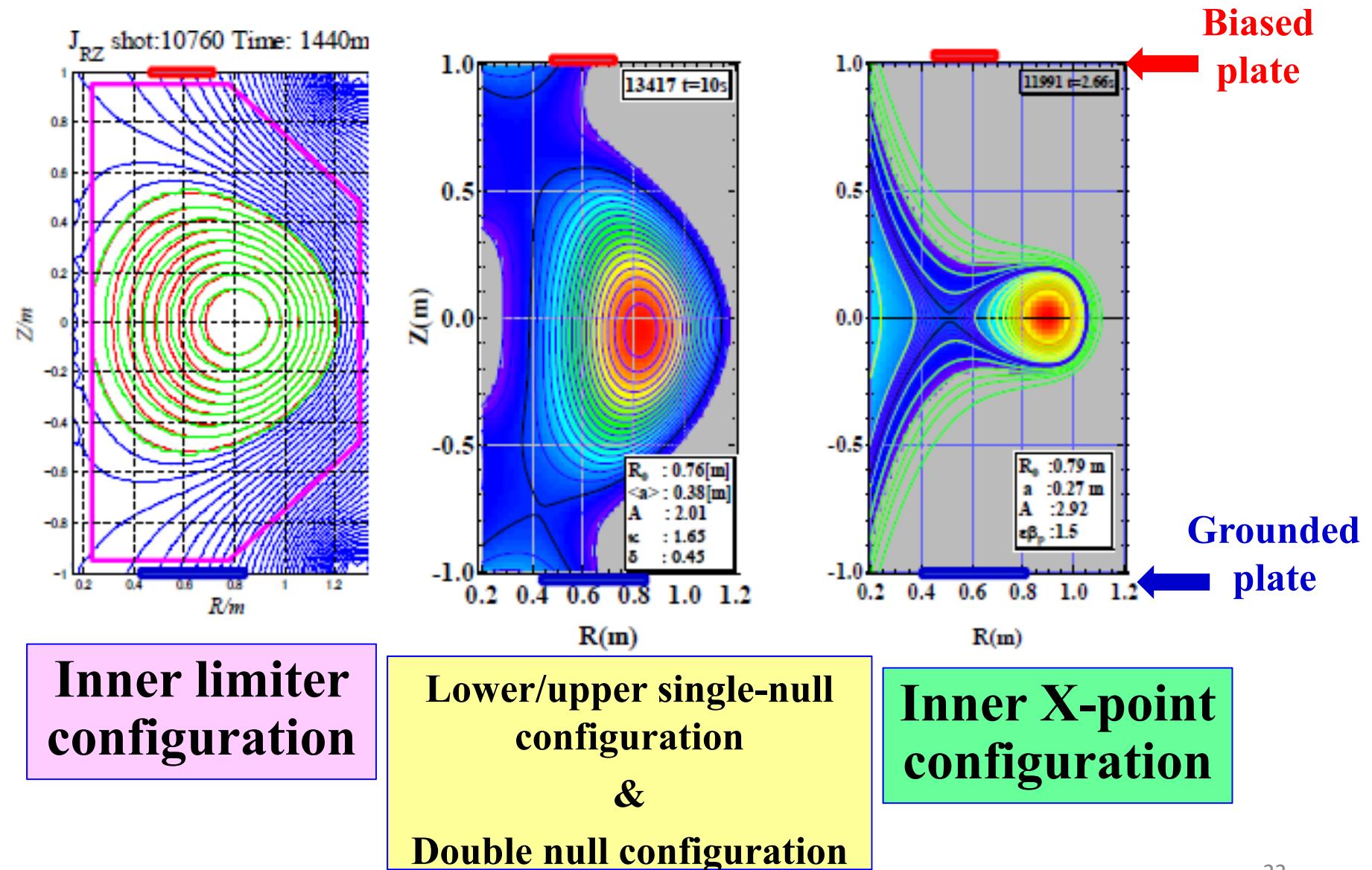
Further assumptions: $d = 0.03 \text{ m}$, $h = L_t \sin \theta_{in} \sim 0.2 \sin(3^\circ) \sim 0.01 \text{ m}$, $D_{\perp} = D_B \sim 2 \text{ m}^2/\text{s}$

$$L_{\parallel f_el} = 18 \text{ m} \Rightarrow L_{\parallel c_el} = 19 \text{ m} < L_c; i_{is} = 0.2 \text{ kA/m}^2, S = dh \sim 1 \times 10^{-4} \text{ m}^2 \Rightarrow I_{is} \sim 0.06 \text{ A}$$

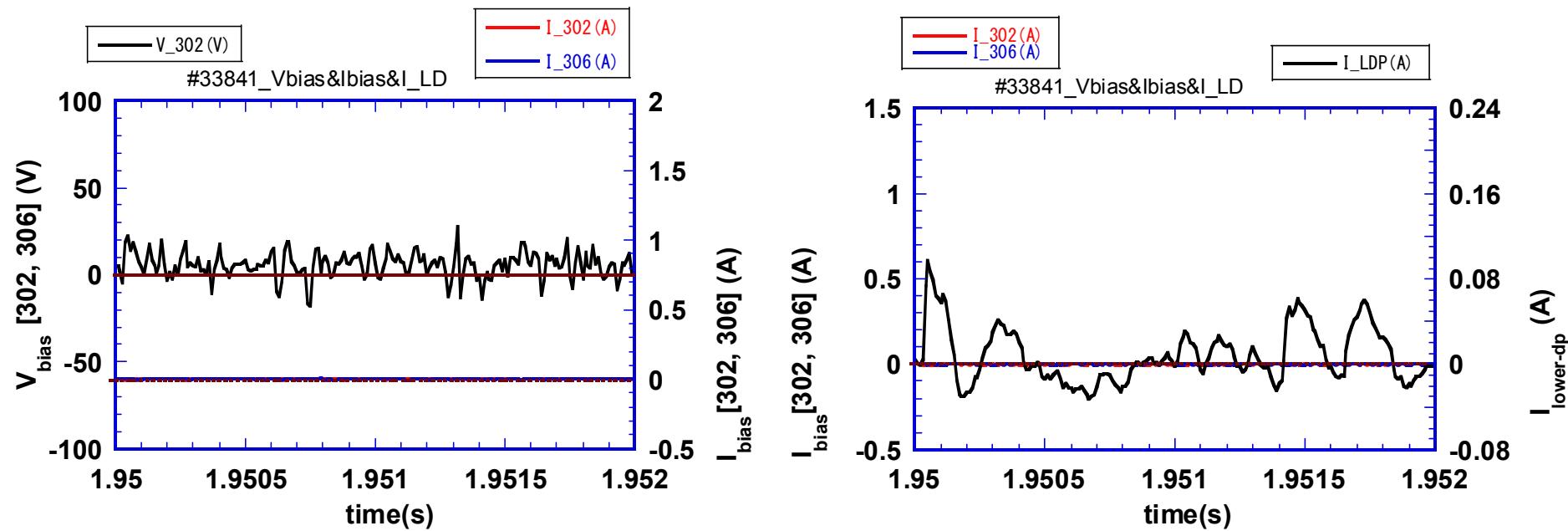
\Rightarrow Expected I_{SOL} for each biased target $I_{SOL} = i_{es} S \sim 10 i_{is} S \sim 0.6 \text{ A}$

◆ Scenario II: Increase in h , T_e and decreased $n_e, q \Rightarrow L_{\parallel c_el} > L_c$ might be realized $\Rightarrow I_{SOL} = i_{is} S \sim 0.06 \text{ A}$

QUESTでこれまでに実現された平衡配位



非バイアス時の上下ダイバータ板での電流



Without biasing of 302 & 306 plates:

The currents in the upper plates are random and much smaller than the current driven by biasing.

The current through the lower plate flows randomly.